
	<h2>SI2341DS-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI2341DS-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 30V 2.5A SOT-23</p> <p>Datenblätter:  SI2341DS-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 78200 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2341DS-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 30V 2.5A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	78200 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	710mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.5A (Ta)
Rds On (Max) @ Id, Vgs	72 mOhm @ 2.8A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	400pF @ 15V
Verpackung	Tape & Reel (TR)







SI2341DS-T1-E3 ist neu im Original, Suche SI2341DS-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2341DS-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2341DS-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2341 VISHAY VISHAY SOT23</p>	 <p>SI2341DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 2.5A SOT-23</p>	 <p>SI2342DS-T1-GE3 Vishay / Siliconix MOSFET N-CH 8V 6A SOT-23</p>	 <p>SI2341DS-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 30V 2.5A SOT-23</p>
 <p>SI2342DS-T1-E3 VISHAY SI2342DS-T1-E3 VISHAY</p>	 <p>SI2338DS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 6A SOT23</p>	 <p>SI2339DS-T1-E3 VISHAY VISHAY SOT-23</p>	 <p>SI2342DS-T1-GE3 Vishay / Spectrol MOSFET N-CH 8V 6A SOT-23</p>

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 SI2333DS-T1-E3	 SI2333DS-T1-E3	 SI2333DS-T1-GE3	 SI2333DS-T1-GE3	 SI2334DS-T1-E3
 SI2334DS-T1-GE3	 SI2334DS-T1-GE3	 SI2335DS-T1	 SI2335DS-T1-E3	 SI2335DS-T1-E3
 SI2335DS-T1-GE3	 SI2335DS-T1-GE3	 SI2336DS-T1-E3	 SI2336DS-T1-GE3	 SI2336DS-T1-GE3
 SI2337DS	 SI2337DS-T1-E3	 SI2337DS-T1-E3	 SI2337DS-T1-GE3	 SI2337DS-T1-GE3
 SI2338DS-T1-E3	 SI2338DS-T1-GE3	 SI2338DS-T1-GE3	 SI2341DS	 SI2341DS-T1-E3
 SI2341DS-T1-GE3	 SI2341DS-T1-GE3	 SI2342DS-T1-E3	 SI2342DS-T1-GE3	 SI2342DS-T1-GE3
 SI2343ADS-T1-GE3	 SI2343CDS	 SI2343CDS-T1-E3	 SI2343CDS-T1-GE3	 SI2343CDS-T1-GE3
 SI2343DS-T1-E3	 SI2343DS-T1-E3	 SI2343DS-T1-GE3	 SI2343DS-T1-GE3	 SI2344DS-E3
 SI2347DS-T1-GE3	 SI2347DS-T1-GE3	 SI2351DS-T1-E3	 SI2351DS-T1-E3	 SI2351DS-T1-GE3
 SI2351DS-T1-GE3	 SI2356DS-T1-GE3	 SI2356DS-T1-GE3	 SI2365EDS	 SI2365EDS-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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